TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2 S C 3 2 6 5

LOW FREQUENCY POWER AMPLIFER APPLICATIONS

POWER SWITCHING APPLICATIONS

• High DC Current Gain : $h_{FE(1)} = 100 \sim 320$

• Low Saturation Voltage: VCE (sat) = 0.4 V (Max.)

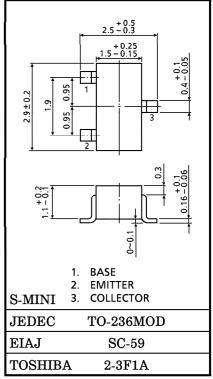
 $(I_C = 500 \text{ mA}, I_B = 20 \text{ mA})$

• Complementary to 2SA1298

MAXIMUM RATINGS (Ta = 25°C)

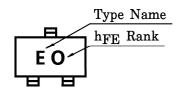
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	v_{CEO}	25	V
Emitter-Base Voltage	$V_{ m EBO}$	5	V
Collector Current	$I_{\mathbf{C}}$	800	mA
Base Current	I_{B}	160	mA
Collector Power Dissipation	PC	200	mW
Junction Temperature	T_{j}	150	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

Unit in mm



Weight: 0.012 g

MARKING



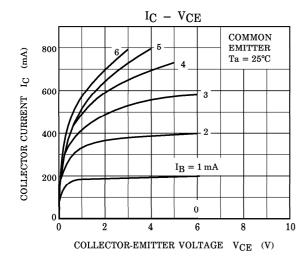
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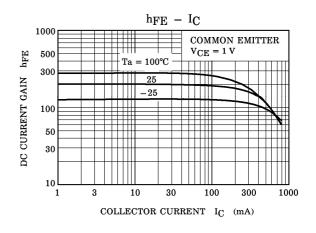
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

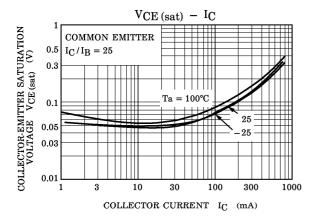
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CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 30 \text{ V}, I_{E} = 0$	_	_	0.1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 5 V, I_{C} = 0$	_	_	0.1	μ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{\rm C} = 10 { m mA}, \; I_{ m B} = 0$	25	_	_	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	$I_{\rm E} = 0.1 { m mA}, \; I_{ m C} = 0$	5	_	_	V
DC Current Gain	hFE (1) (Note)	$V_{ m CE} = 1 m V, I_{ m C} = 100 mA$	100	_	320	
	h _{FE} (2)	$V_{CE} = 1 \text{ V}, I_{C} = 800 \text{ mA}$	40	_	_	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{\rm C} = 500 {\rm mA}, \; I_{\rm B} = 20 {\rm mA}$	_	_	0.4	V
Base-Emitter Voltage	$V_{ m BE}$	$V_{CE} = 1 \text{ V}, I_{C} = 10 \text{ mA}$	0.5	_	0.8	V
Transition Frequency	$ m f_{T}$	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$		120		MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		13	_	pF

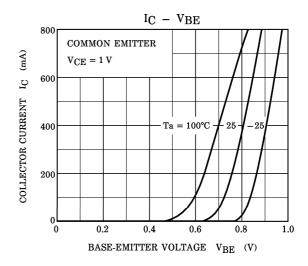
Note : hFE (1) Classification O : 100~200, Y : 160~320

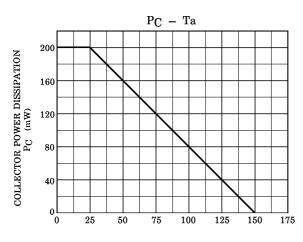
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AMBIENT TEMPERATURE Ta (°C)

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